Preferred Device

General Purpose Transistor

NPN Silicon

Features

• Pb-Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V_{CEO}	40	Vdc
Collector - Base Voltage	V_{CBO}	60	Vdc
Emitter – Base Voltage	V_{EBO}	6.0	Vdc
Collector Current – Continuous	Ic	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) @T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) @T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

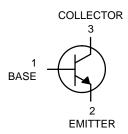
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



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SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAM



1AM = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT3904LT1	SOT-23	3000 / Tape & Reel
MMBT3904LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBT3904LT3	SOT-23	10,000/Tape & Reel
MMBT3904LT3G	SOT-23 (Pb-Free)	10,000/Tape & Reel

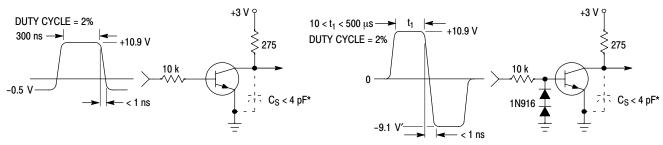
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Chara	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS			•	•	•
Collector-Emitter Breakdown Voltage (V _{(BR)CEO}	40	_	Vdc	
Collector-Base Breakdown Voltage (I _C	= 10 μAdc, I _E = 0)	V _{(BR)CBO}	60	-	Vdc
Emitter – Base Breakdown Voltage (I _E =	10 μAdc, I _C = 0)	V _{(BR)EBO}	6.0	-	Vdc
Base Cutoff Current (V _{CE} = 30 Vdc, V _{EE}	₃ = 3.0 Vdc)	I _{BL}	_	50	nAdc
Collector Cutoff Current (V _{CE} = 30 Vdc,	V _{EB} = 3.0 Vdc)	I _{CEX}	_	50	nAdc
ON CHARACTERISTICS (Note 3)				•	
	H _{FE}	40 70 100 60 30	300	-	
	V _{CE(sat)}	- -	0.2 0.3	Vdc	
$\begin{aligned} \text{Base-Emitter Saturation Voltage} \\ \text{(I}_{\text{C}} &= 10 \text{ mAdc, I}_{\text{B}} = 1.0 \text{ mAdc)} \\ \text{(I}_{\text{C}} &= 50 \text{ mAdc, I}_{\text{B}} = 5.0 \text{ mAdc)} \end{aligned}$	V _{BE(sat)}	0.65 -	0.85 0.95	Vdc	
SMALL-SIGNAL CHARACTERISTICS		•			
Current - Gain - Bandwidth Product (I _C	= 10 mAdc, V _{CE} = 20 Vdc, f = 100 MHz)	f _T	300	-	MHz
Output Capacitance ($V_{CB} = 5.0 \text{ Vdc}, I_{E} = 1.0 \text{ Vdc}$	= 0, f = 1.0 MHz)	C _{obo}	-	4.0	pF
Input Capacitance ($V_{EB} = 0.5 \text{ Vdc}$, $I_{C} =$	0, f = 1.0 MHz)	C _{ibo}	-	8.0	pF
Input Impedance ($V_{CE} = 10 \text{ Vdc}$, $I_{C} = 1$.	0 mAdc, f = 1.0 kHz)	h _{ie}	1.0	10	kΩ
Voltage Feedback Ratio (V _{CE} = 10 Vdc,	I _C = 1.0 mAdc, f = 1.0 kHz)	h _{re}	0.5	8.0	X 10 ⁻⁴
Small – Signal Current Gain (V _{CE} = 10 V	h _{fe}	100	400	-	
Output Admittance ($V_{CE} = 10 \text{ Vdc}, I_{C} =$	h _{oe}	1.0	40	μmhos	
Noise Figure (V_{CE} = 5.0 Vdc, I_{C} = 100 μ	NF	-	5.0	dB	
SWITCHING CHARACTERISTICS		•	•		•
Delay Time	$(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc},$	t _d	_	35	
Rise Time	$I_C = 10 \text{ mAdc}, I_{B1} = 1.0 \text{ mAdc})$	t _r	_	35	ns
Storage Time	(V _{CC} = 3.0 Vdc,	t _s	-	200	no
Fall Time	$I_C = 10 \text{ mAdc}, I_{B1} = I_{B2} = 1.0 \text{ mAdc}$	t _f	_	50	ns

^{3.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

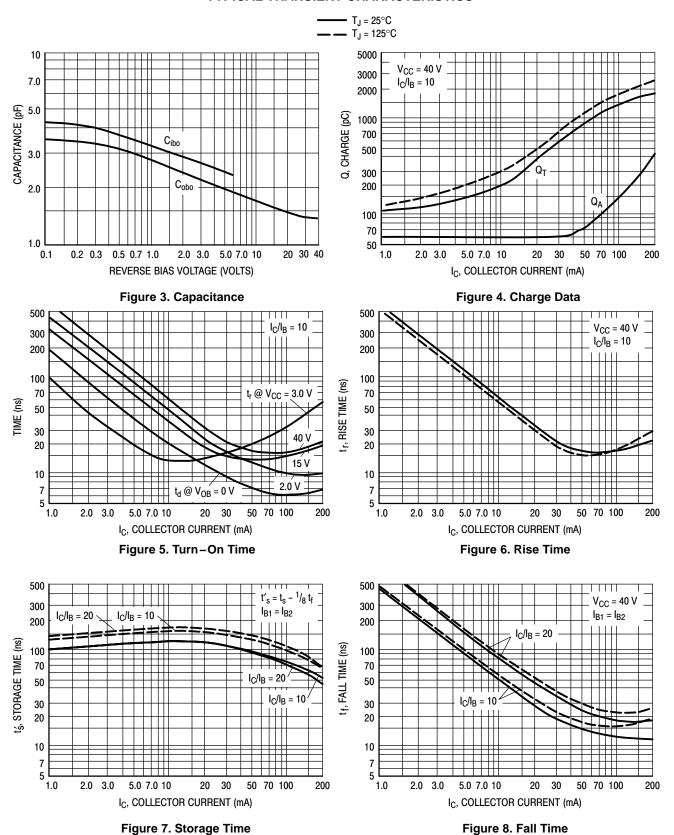


^{*} Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit

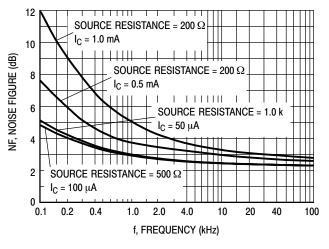
Figure 2. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS



TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS **NOISE FIGURE VARIATIONS**

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



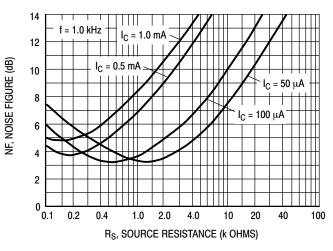
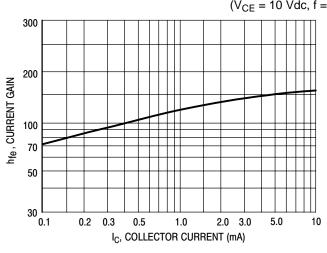


Figure 9.

Figure 10.

h PARAMETERS



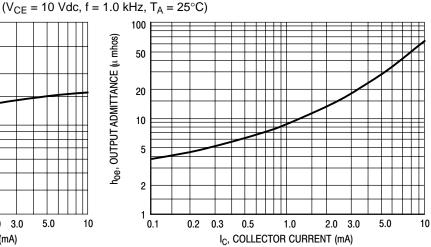
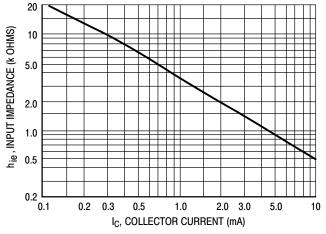
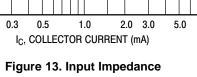


Figure 11. Current Gain

10





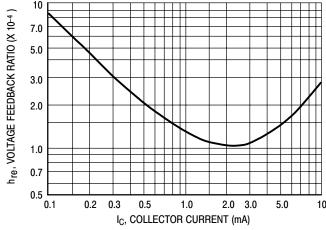


Figure 12. Output Admittance

Figure 14. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

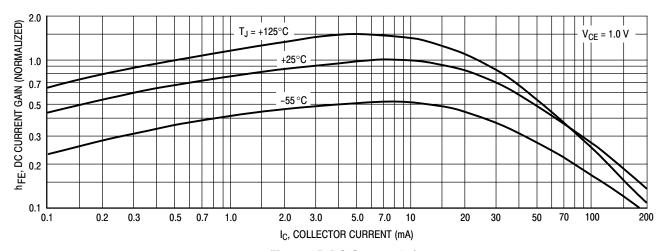


Figure 15. DC Current Gain

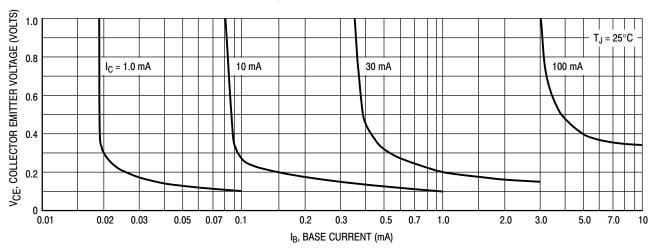


Figure 16. Collector Saturation Region

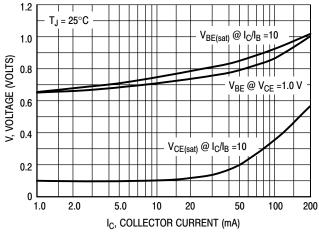


Figure 17. "ON" Voltages

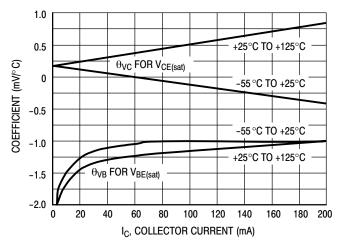
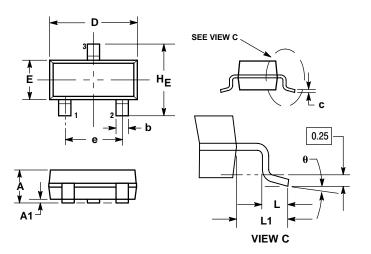


Figure 18. Temperature Coefficients

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AN



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14 5M 1982
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. 318–01 THRU –07 AND –09 OBSOLETE, NEW STANDARD 318–08.

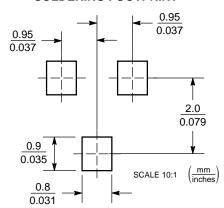
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	MON	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

PIN 1. BASE 2. EMITTER

3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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